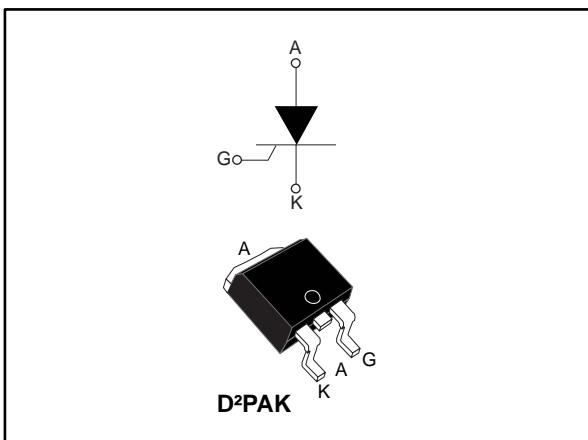


## High temperature 16 A SCRs

Datasheet - production data



### Description

Designed with high immunity switching to external surges, this device offers robust switching up to its 150°C maximum  $T_j$ .

The combination of noise immunity and low gate triggering current allows to design strong and compact control circuit.

Table 1: Device summary

Order code	Package	$V_{DRM}/V_{RRM}$	$I_{GT}$
TN1605H-6G	D²PAK	600	6 mA

### Features

- High junction temperature:  $T_j = 150^\circ\text{C}$
- Gate triggering current  $I_{GT} = 6 \text{ mA}$
- High noise immunity  $dV/dt = 200 \text{ V}/\mu\text{s}$  up to 150 °C
- Blocking voltage  $V_{DRM}/V_{RRM} = 600 \text{ V}$
- High turn-on current rise  $di/dt$ : 100 A/ $\mu\text{s}$
- ECOPACK®2 compliant component

### Applications

- Motorbikes voltage regulator circuits
- Inrush current limiting circuits
- Motor control circuits and starters
- Light dimmers
- Solid state relays

# 1 Characteristics

Table 2: Absolute maximum ratings (limiting values,  $T_j = 25^\circ\text{C}$  unless otherwise specified)

Symbol	Parameter			Value	Unit
$I_{T(\text{RMS})}$	RMS on-state current (180° conduction angle)	$T_c = 133^\circ\text{C}$		16	A
$I_{T(\text{AV})}$	Average on-state current (180° conduction angle)	$T_c = 133^\circ\text{C}$		10	A
		$T_c = 138^\circ\text{C}$		8	
		$T_c = 142^\circ\text{C}$		6	
$I_{TSM}$	Non repetitive surge peak on-state current	$t_p = 8.3 \text{ ms}$	$T_j \text{ initial} = 25^\circ\text{C}$	153	A
		$t_p = 10 \text{ ms}$		140	
$I^2t$	$I^2t$ value for fusing	$t_p = 10 \text{ ms}$		98	$\text{A}^2\text{s}$
$dI/dt$	Critical rate of rise of on-state current	$I_G = 2 \times I_{GT}, t_r \leq 100 \text{ ns}$	$f = 60 \text{ Hz}$	100	$\text{A}/\mu\text{s}$
$V_{DRM}/V_{RRM}$	Repetitive peak off-state voltage		$T_j = 150^\circ\text{C}$	600	V
$V_{DSM}/V_{RSM}$	Non repetitive surge peak off-state voltage	$t_p = 10 \text{ ms}$		700	V
$P_G(\text{AV})$	Average gate power dissipation		$T_j = 150^\circ\text{C}$	1	W
$V_{RGM}$	Maximum peak reverse gate voltage			5	V
$I_{GM}$	Peak gate current	$t_p = 20 \mu\text{s}$	$T_j = 150^\circ\text{C}$	4	A
$T_{stg}$	Storage junction temperature range			-40 to +150	$^\circ\text{C}$
$T_j$	Operating junction temperature range			-40 to +150	$^\circ\text{C}$

Table 3: Dynamic characteristics

Symbol	Parameter	$T_j$		Value	Unit
$I_{GT}$	$V_D = 12 \text{ V}, R_L = 33 \Omega$	$25^\circ\text{C}$	Min.	3.5	mA
		Typ.		4.5	
		Max.		6	
		Max.		1.3	V
$V_{GD}$	$V_D = 600, R_L = 3.3 \text{ k}\Omega$	$150^\circ\text{C}$	Min.	0.15	V
$I_L$	$I_G = 1.2 \times I_{GT}$	$25^\circ\text{C}$	Max.	40	mA
$I_H$	$I_T = 500 \text{ mA, gate open}$		Max.	20	
$dV/dt$	$V_D = 402 \text{ V, gate open}$	$150^\circ\text{C}$	Min.	200	$\text{V}/\mu\text{s}$
$t_{gt}$	$I_{TM} = 32 \text{ A, } V_D = 402 \text{ V, } I_G = 12 \text{ mA, } (dI/dt)_{\text{off}} = 0.2 \text{ A}/\mu\text{s}$	$25^\circ\text{C}$	Typ.	1.9	$\mu\text{s}$
$t_q$	$I_{TM} = 32 \text{ A, } V_D = 402 \text{ V, } (dI/dt)_{\text{off}} = 30 \text{ A}/\mu\text{s, } V_R = 25 \text{ V, } dV_D/dt = 20 \text{ V}/\mu\text{s}$	$150^\circ\text{C}$	Typ.	70	$\mu\text{s}$

**Table 4: Static electrical characteristics**

<b>Symbol</b>	<b>Test conditions</b>	<b>T<sub>J</sub></b>		<b>Value</b>	<b>Unit</b>
V <sub>TM</sub>	I <sub>TM</sub> = 32 A, t <sub>p</sub> = 380 µs	25 °C	Max.	1.6	V
V <sub>TO</sub>	Threshold on-state voltage	150 °C	Max.	0.82	V
R <sub>D</sub>	Dynamic resistance	150 °C	Max.	25	mΩ
I <sub>DRM</sub> /I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub>	25 °C	Max.	5	µA
		125 °C		1.5	mA
		150 °C		3.1	

**Table 5: Thermal resistance**

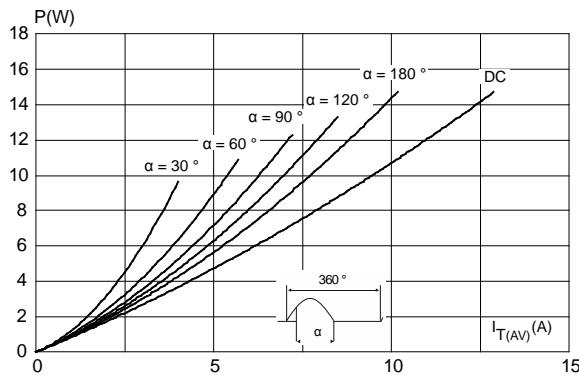
<b>Symbol</b>	<b>Parameter</b>		<b>Value</b>	<b>Unit</b>
R <sub>th(j-c)</sub>	Junction to case (DC)	Max.	1.1	°C/W
R <sub>th(j-a)</sub>	Junction to ambient (DC)	S <sup>(1)</sup> = 1 cm <sup>2</sup>	Typ.	45

**Notes:**

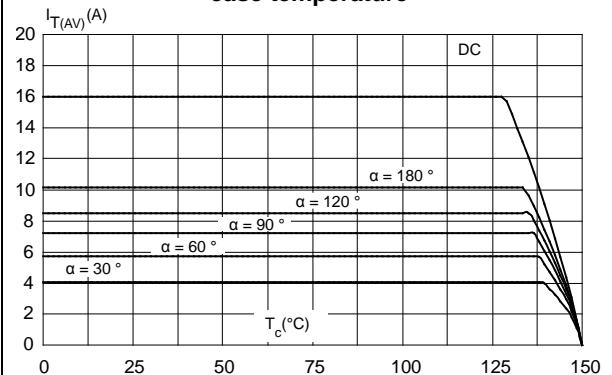
(1)S = copper surface under tab

## 1.1 Characteristics (curves)

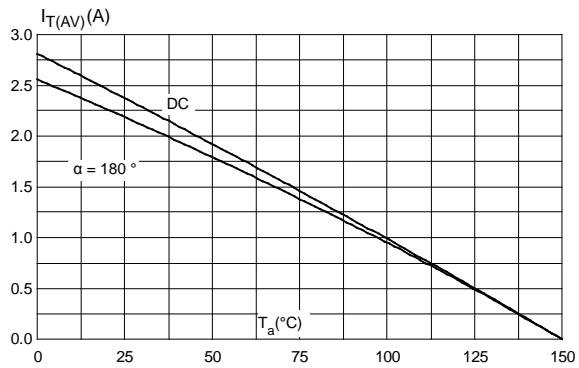
**Figure 1: Maximum average power dissipation versus average on-state current**



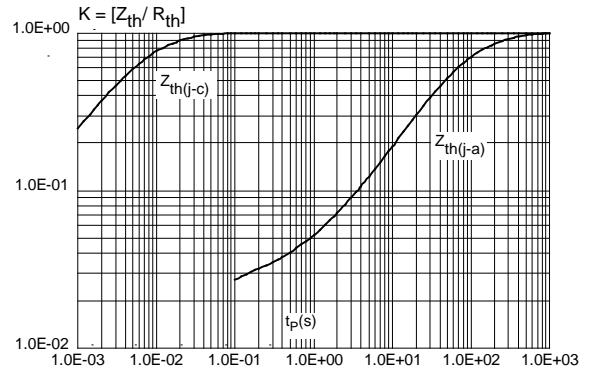
**Figure 2: Average and DC on-state current versus case temperature**



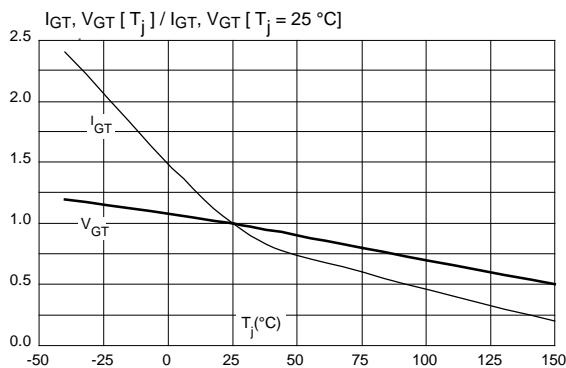
**Figure 3: Average and DC on-state current versus ambient temperature**



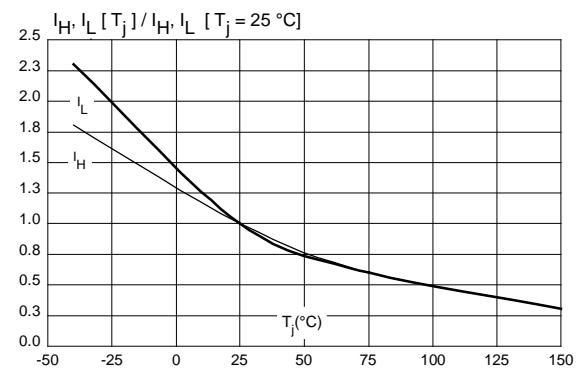
**Figure 4: Relative variation of thermal impedance versus pulse duration**



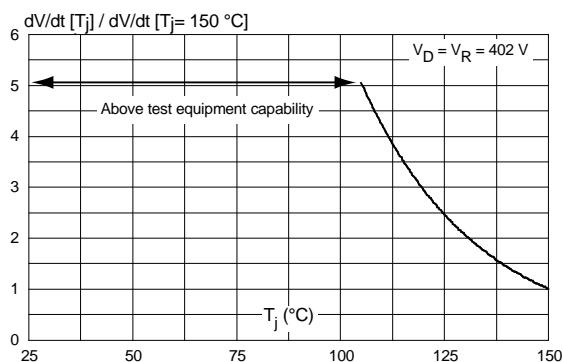
**Figure 5: Relative variation of gate trigger current and gate voltage versus junction temperature (typical values)**



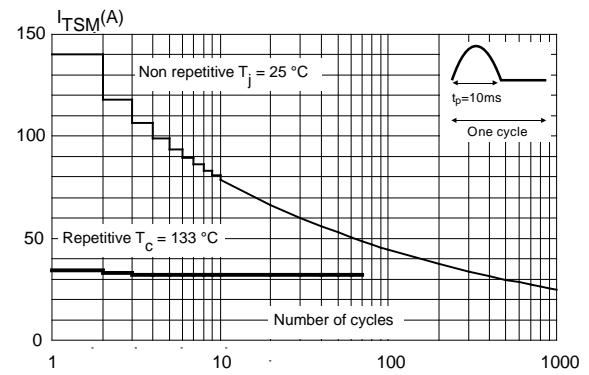
**Figure 6: Relative variation of holding and latching current versus junction temperature (typical values)**



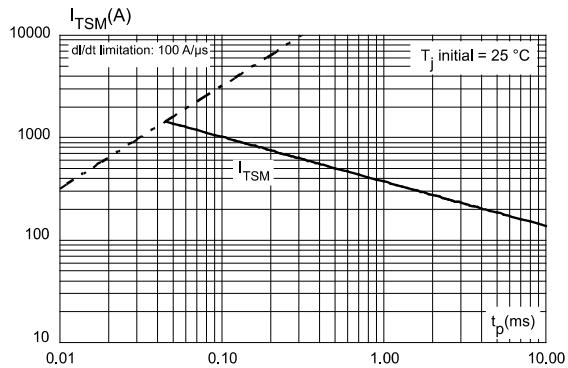
**Figure 7: Relative variation of static dV/dt immunity versus junction temperature (typical values)**



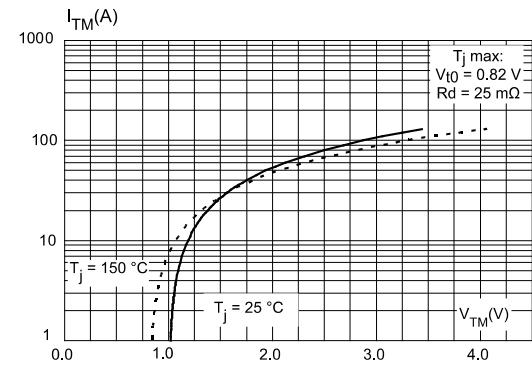
**Figure 8: Surge peak on-state current versus number of cycles**



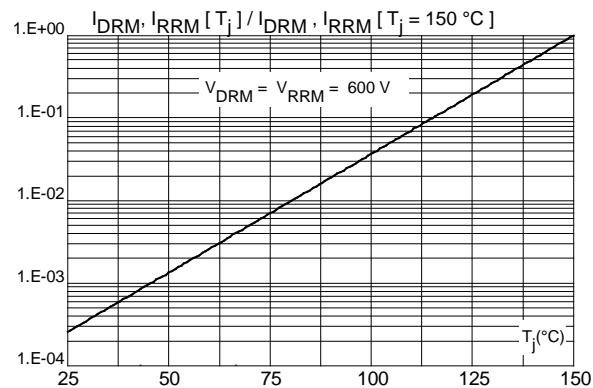
**Figure 9: Non repetitive surge peak on-state current versus sinusoidal pulse width ( $t_p < 10$  ms).**



**Figure 10: On-state characteristics (maximum values)**



**Figure 11: Relative variation of leakage current versus junction temperature ( $t_P < 10ms$ )**



## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
ECOPACK® is an ST trademark.

- Epoxy meets UL 94,V0
- Lead-free package

### 2.1 D<sup>2</sup>PAK package information

Figure 12: D<sup>2</sup>PAK package outline

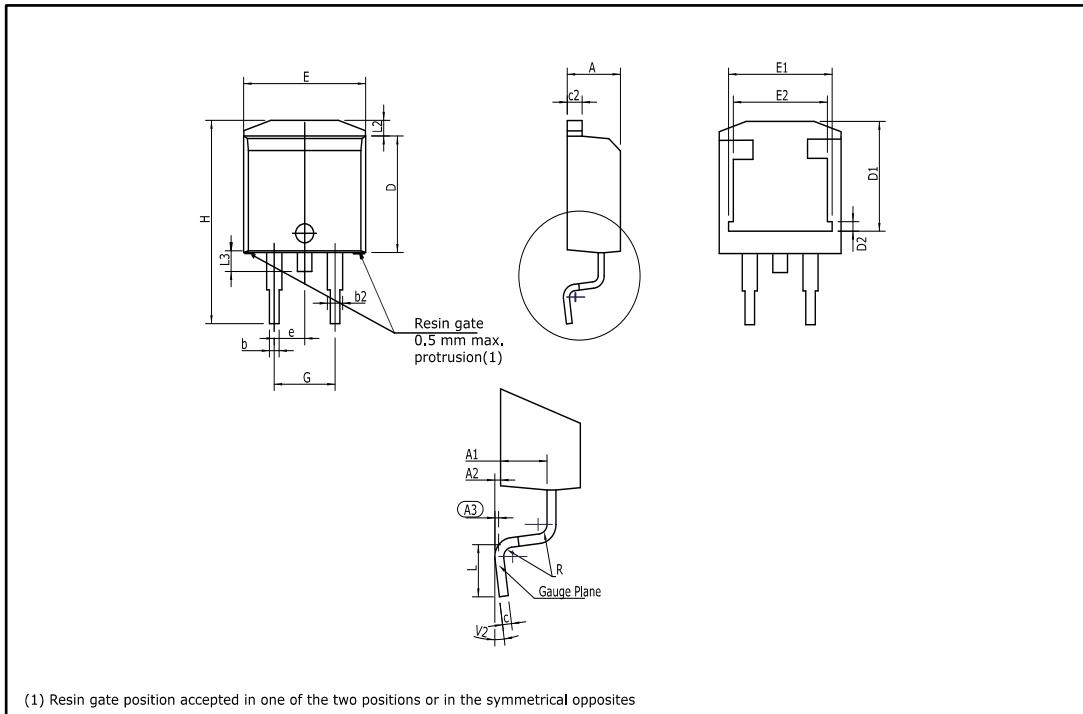
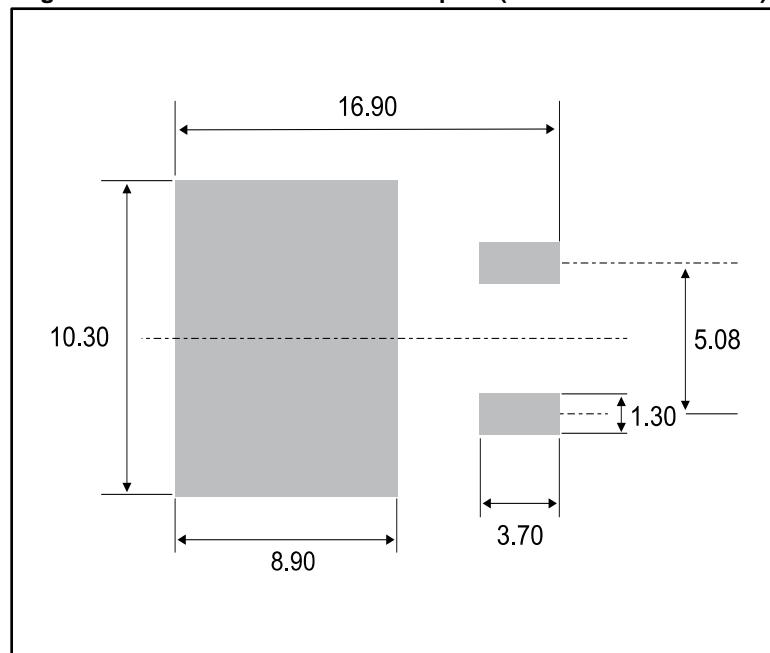


Table 6: D<sup>2</sup>PAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches <sup>(1)</sup>		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.1693		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0012		0.0091
A3		0.25			0.0098	
b	0.70		0.93	0.0276		0.0366
b2	1.25		1.7	0.0492		0.0669
c	0.45		0.60	0.0177		0.0236
c2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3524		0.3681
D1	7.50		8.00	0.2953		0.3150
D2	1.30		1.70	0.0512		0.0669
e	2.54			0.1		
E	10.00		10.28	0.3937		0.4047
E1	8.30		8.70	0.3268		0.3425
E2	6.85		7.25	0.2697		0.2854
G	4.88		5.28	0.1921		0.2079
H	15		15.85	0.5906		0.6240
L	1.78		2.28	0.0701		0.0898
L2	1.27		1.40	0.0500		0.0551
L3	1.40		1.75	0.0551		0.0689
R		0.40			0.0157	
V2	0°		8°	0°		8°

**Notes:**

(1) Dimensions in inches are given for reference only

**Figure 13: D<sup>2</sup>PAK recommended footprint (dimensions are in mm)**

### 3 Ordering information

Figure 14: Ordering information scheme

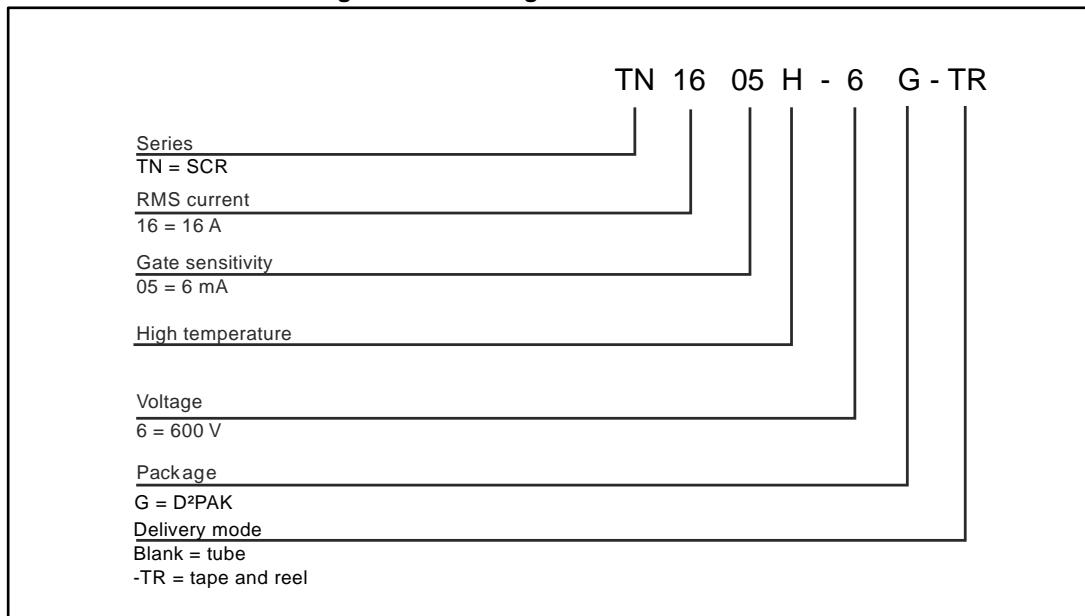


Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN1605H-6G	TN1605H6	D <sup>2</sup> PAK	1.5 g	50	Tube
TN1605H-6G-TR				1000	Tape and reel

### 4 Revision history

Table 8: Document revision history

Date	Revision	Changes
18-May-2017	1	Initial release.
26-Jun-2017	2	Updated <a href="#">Table 5: "Thermal resistance".</a>